

MOSFET Maximum Ratings T₁ = 25°C unless otherwise noted.

Symbol	Parameter		Ratings	Units	
V _{DSS}	Drain-to-Source Voltage		60	V	
V _{GS}	Gate-to-Source Voltage		±20	V	
	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	110	•	
I _D	Pulsed Drain Current	T _C = 25°C	See Figure 4	Α	
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	614	mJ	
D	Power Dissipation		333	W	
P _D	Derate Above 25°C		2.22	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case		0.45	°C/W	
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	43	°C/W	

Notes:

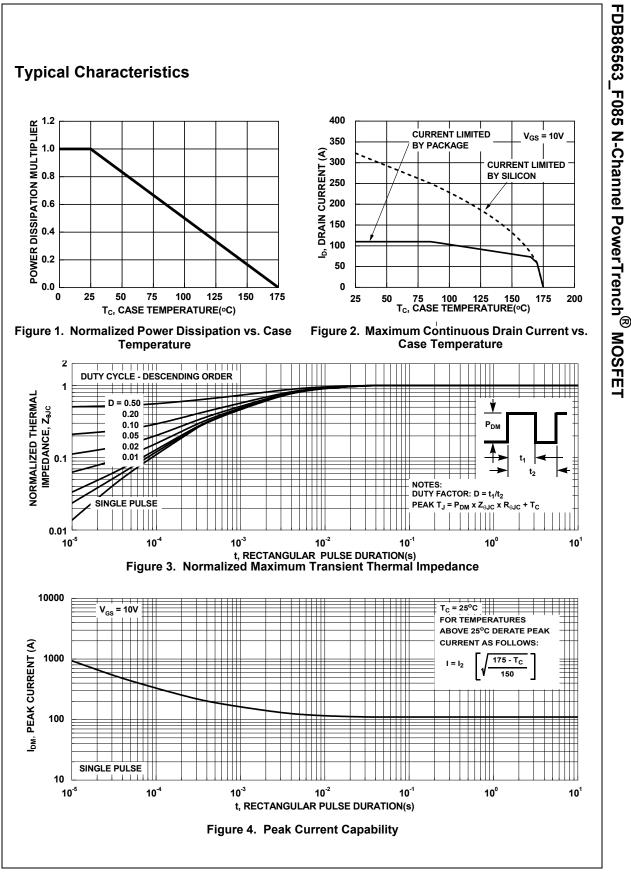
1: Current is limited by bondwire configuration.

2: Starting T_J = 25°C, L = 0.3mH, I_{AS} = 64A, V_{DD} = 60V during inductor charging and V_{DD} = 0V during time in avalanche. 3: $R_{0,JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design, while $R_{\theta JA}$ is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

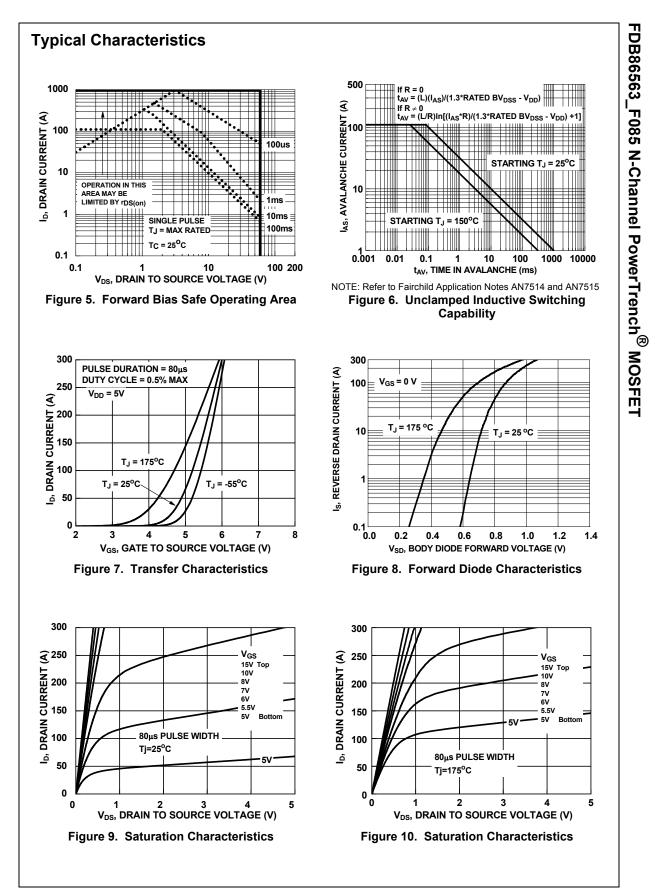
Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDB86563	FDB86563_F085	D2-PAK(TO-263)	330mm	24mm	800units

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
Off Cha	racteristics						
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA, '	V _{GS} = 0V	60	-	-	V
	Drain-to-Source Leakage Current	V _{DS} =60V,		-	-	1	μA
I _{DSS}		$V_{GS} = 0V$	T _J = 175 ^o C (Note 4)	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA
On Cha	racteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$		2.0	2.9	4.0	V
	Drain to Source On Resistance	I _D = 80A,	T _J = 25 ^o C	-	1.6	1.8	mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 10V	$T_{J} = 175^{\circ}C$ (Note 4)	-	2.8	3.2	mΩ
C _{iss} C _{oss}	Input Capacitance Output Capacitance	− V _{DS} = 30V, V _{GS} = 0V, f = 1MHz		-	10100 2355	-	pF pF
C _{iss}				-		-	
C _{rss}	Reverse Transfer Capacitance			-	186	-	pF
R _q	Gate Resistance	f = 1MHz		-	4.5	-	Ω
Q _{g(ToT)}	Total Gate Charge	$V_{GS} = 0 \text{ to } 10V \\ V_{GS} = 0 \text{ to } 2V \\ I_D = 80A$		-	126	163	nC
$Q_{g(th)}$	Threshold Gate Charge			-	19	-	nC
Q _{gs}	Gate-to-Source Gate Charge			-	48	-	nC
Q _{gd}	Gate-to-Drain "Miller" Charge		-	-	18	-	nC
	ng Characteristics					040	
t _{on}	Turn-On Time			-	-	213	ns
t _{d(on)}	Turn-On Delay Rise Time		- 904	-	28 110	-	ns
r ······	Turn-Off Delay	$V_{DD} = 30V,$ $V_{CO} = 10V$		-	79	-	ns ns
d(off)	Fall Time	V _{GS} = 10V, R _{GEN} = 6Ω		-	60	-	ns
t _f	Turn-Off Time			-	-	- 250	ns
t _{off}				-		200	113
Drain-S	ource Diode Characteristics						
V _{SD}	Source-to-Drain Diode Voltage	I _{SD} =80A, V		-	-	1.25	V
		I _{SD} = 40A, V _{GS} = 0V		-	-	1.2	V
t _{rr}	Reverse-Recovery Time	I _F = 80A, dI _{SD} /dt = 100A/μs V _{DD} = 48V		-	98	129	ns
Q _{rr}	Reverse-Recovery Charge				150	230	nC

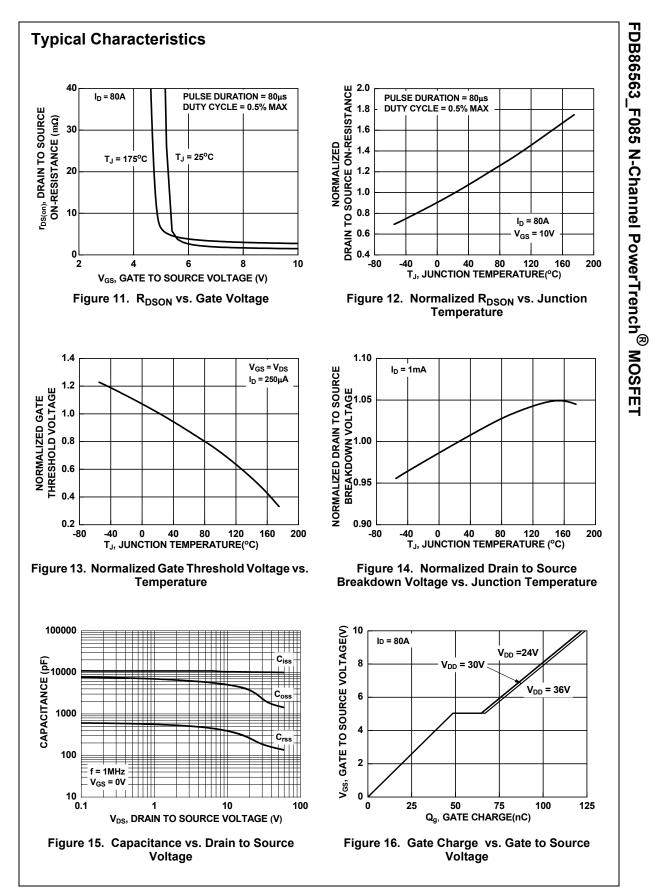


FDB86563_F085 Rev. C1



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4



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